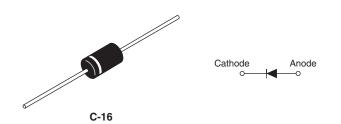
Vishay Semiconductors

Schottky Rectifier, 3.3 A



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| PRODUCT SUMMARY | | | | | |
|----------------------------------|----------------------|--|--|--|--|
| Package | DO-201AD (C-16) | | | | |
| I _{F(AV)} | 3.3 A | | | | |
| V _R | 90 V, 100 V | | | | |
| V _F at I _F | See Electrical table | | | | |
| I _{RM} max. | 3.0 mA at 125 °C | | | | |
| T _J max. | 150 °C | | | | |
| Diode variation | Single die | | | | |
| E _{AS} | 3.0 mJ | | | | |

FEATURES

- Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



HALOGEN

FREE Available

- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

DESCRIPTION

The VS-31DQ... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-----------------------------------|-------------------------------|-------------|-------|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | |
| I _{F(AV)} | Rectangular waveform | 3.3 | A | | | | |
| V _{RRM} | | 90/100 | V | | | | |
| I _{FSM} | t _p = 5 μs sine | 210 | A | | | | |
| V _F | 3 Apk, T _J = 25 °C | 0.85 | V | | | | |
| TJ | | - 40 to 150 | °C | | | | |

| VOLTAGE RATINGS | | | | | | | | |
|---|------------------|-----------|--------------|-----------|--------------|-------|--|--|
| PARAMETER | SYMBOL | VS-31DQ09 | VS-31DQ09-M3 | VS-31DQ10 | VS-31DQ10-M3 | UNITS | | |
| Maximum DC reverse voltage | V _R | | | | | | | |
| Maximum working peak reverse voltage | V _{RWM} | 90 | 90 | 100 | 100 | V | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|--|--------------------|---|---|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | | |
| Maximum average forward current See fig. 4 | I _{F(AV)} | AV) 50 % duty cycle at $T_L = 108$ °C, rectangular waveform | | 3.3 | | | |
| Maximum peak one cycle non-repetitive surge current | 1 | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and with rated | 210 | A | | |
| See fig. 6 | IFSM | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 34 | | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 1 A, L = 6 mH | | 3.0 | mJ | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 0.5 | А | | |

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| ELECTRICAL SPECIFICATIONS | | | | | | |
|--|--------------------------------|---|---------------------------------------|--------|-------|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS | |
| | V _{FM} ⁽¹⁾ | 3 A | T ₁ = 25 °C | 0.85 | V | |
| Maximum forward voltage drop See fig. 1 | | 6 A | 1j=23 0 | 0.97 | | |
| | | 3 A | T 105 %O | 0.69 | | |
| | | 6 A | T _J = 125 °C | 0.80 | | |
| Maximum reverse leakage current | I (1) | T _J = 25 °C | V Deted V | 1 | mA | |
| See fig. 4 | | T _J = 125 °C | V _R = Rated V _R | 3 | IIIA | |
| Typical junction capacitance | C _T | V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C | | 110 | pF | |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body | | 9.0 | nH | |
| Maximum voltage rate of charge | dV/dt | Rated V _R 10 000 | | | V/µs | |

Note

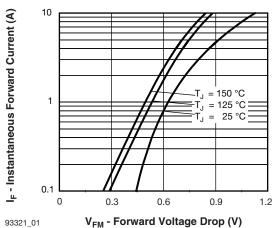
⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|--|-------------------------------------|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum junction and storage temperature range | T _J ⁽¹⁾ , T _{Stg} | | - 40 to 150 | °C | | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | DC operation Without cooling fin | 80 | °C/W | | |
| Typical thermal resistance, junction to lead | R _{thJL} | DC operation | 15 | 0/11 | | |
| Approvimeto weight | | | 1.2 | g | | |
| Approximate weight | | | 0.042 | oz. | | |
| | | | 31DQ09 | | | |
| Marking device | | Case style C-16 | 31DQ10 | | | |

Note

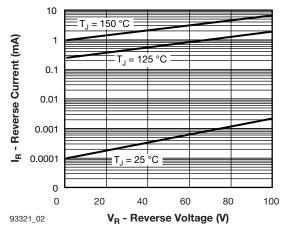
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

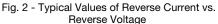
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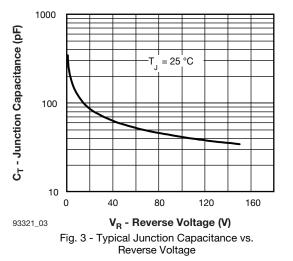


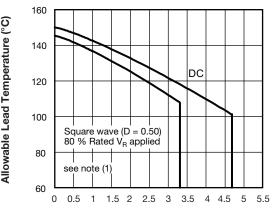
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Fig. 1 - Maximum Forward Voltage Drop Characteristics









93321_04 **I_{F(AV)} - Average Forward Current (A)** Fig. 4 - Maximum Allowable Lead Temperature vs. Average Forward Current

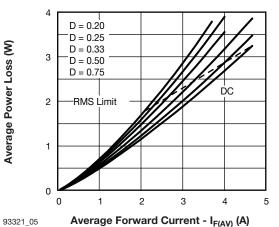


Fig. 5 - Forward Power Loss Characteristics

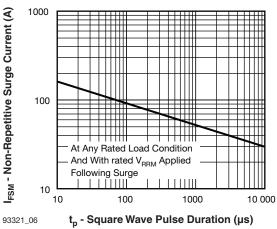


Fig. 6 - Maximum Non-Repetitive Surge Current

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJL}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

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ORDERING INFORMATION TABLE

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VISHA

| Device code | VS- | 31 | D | Q | 10 | TR | -M3 | |
|-------------|---|--|--|-----|----------------------------------|----|---------|------------------------------------|
| | | 2 | 3 | 4 | 5 | 6 | 7 | 1 |
| | 1 - 2 - 3 - 4 - 5 - 6 - 7 - | 31 = D = 1 Q = 10 = • TR • No Envi | Curren DO-201 Schottky Voltage = Tape ne = Bu ronmen | • | , 3.3 A e ries el packa | ge | complia | - 09 = 90 V 10 = 100 V |
| | | | | . , | | | • | ant d terminations lead (Pb)-fr |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|------------------|------------------------|-----------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-31DQ09 | 500 | 500 | Bulk | | | |
| VS-31DQ09TR | 1200 | 1200 | Tape and reel | | | |
| VS-31DQ09-M3 | 500 | 500 | Bulk | | | |
| VS-31DQ09TR-M3 | 1200 | 1200 | Tape and reel | | | |
| VS-31DQ10 | 500 | 500 | Bulk | | | |
| VS-31DQ10TR | 1200 | 1200 | Tape and reel | | | |
| VS-31DQ10-M3 | 500 | 500 | Bulk | | | |
| VS-31DQ10TR-M3 | 1200 | 1200 | Tape and reel | | | |

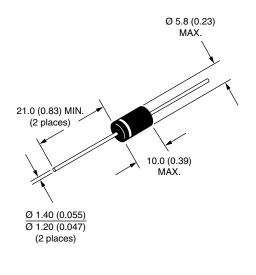
| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?95242 | | | | |
| Part marking information | www.vishay.com/doc?95304 | | | | |
| Packaging information | www.vishay.com/doc?95338 | | | | |
| SPICE model | www.vishay.com/doc?95300 | | | | |

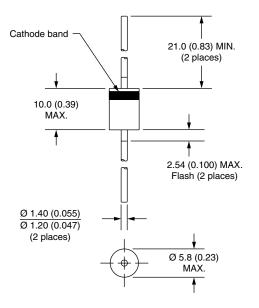




Axial DO-201AD (C-16)

DIMENSIONS in millimeters (inches)





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